







TPS62160, TPS62161, TPS62162, TPS62163

Support &

20

SLVSAM2E - NOVEMBER 2011 - REVISED MAY 2017

# TPS6216x 3-V to 17-V, 1-A Step-Down Converters with DCS-Control™

#### 1 Features

Texas

DCS-Control<sup>™</sup> Topology

INSTRUMENTS

- Input Voltage Range from 3 V to 17 V
- Up to 1-A Output Current
- Adjustable Output Voltage From 0.9 V to 6 V
- **Fixed Output Voltage Versions**
- Seamless Power Save Mode Transition
- Typically 17-µA Quiescent Current
- Power Good Output
- 100% Duty Cycle Mode
- Short Circuit Protection
- **Over Temperature Protection**
- Pin to Pin Compatible With TPS62170 and **TPS62125**
- Available in 3.00 mm x 3.00 mm 8-Pin VSSOP and 2.00 mm × 2.00 mm 8-Pin WSON Packages
- Create a Custom Design using the TPS62160 with the WEBENCH® Power Designer

# 2 Applications

- Standard 12-V Rail Supplies ٠
- POL Supply From Single or Multiple Li-Ion Battery
- LDO Replacement
- Embedded Systems
- Digital Still Camera, Video
- Mobile PCs, Tablet-PCs, Modems

# **3** Description

The TPS6216x device family are easy to use synchronous step-down DC/DC converters optimized for applications with high power density. A high switching frequency of typically 2.25 MHz allows the use of small inductors and provides fast transient response as well as high output voltage accuracy by utilization of the DCS-Control<sup>™</sup> topology.

With its wide operating input voltage range of 3 V to 17 V, the devices are ideally suited for systems powered from either a Li-Ion or other battery as well as from 12-V intermediate power rails. It supports up to 1-A continuous output current at output voltages between 0.9 V and 6 V (with 100% duty cycle mode).

Power sequencing is also possible by configuring the enable and open-drain power good pins.

In power save mode, the devices show quiescent current of about 17 µA from VIN. Power save mode, entered automatically and seamlessly if the load is small, maintains high efficiency over the entire load range. In shutdown mode, the device is turned off and shutdown current consumption is less than 2 µA.

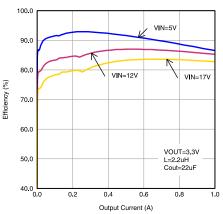
The device, available in adjustable and fixed output voltage versions, is packaged in an 8-pin WSON package measuring 2.00 mm × 2.00 mm (DSG) or 8pin VSSOP package measuring 3.00 mm x 3.00 mm (DGK).

#### Device Information<sup>(1)</sup>

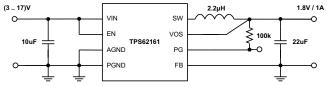
PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS6216x	WSON (8)	2.00 mm x 2.00 mm
TPS62160	VSSOP (8)	3.00 mm x 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

#### **Efficiency vs Output Current**



# **Typical Application Schematic**



# **Table of Contents**

1	Feat	tures 1
2	Арр	lications 1
3	Des	cription 1
4	Rev	ision History 2
5	Dev	ice Voltage Options 4
6	Pin	Configuration and Functions 4
7	Spe	cifications5
	7.1	Absolute Maximum Ratings 5
	7.2	ESD Ratings5
	7.3	Recommended Operating Conditions 5
	7.4	Thermal Information5
	7.5	Electrical Characteristics6
	7.6	Typical Characteristics 7
8	Deta	ailed Description8
	8.1	Overview
	8.2	Functional Block Diagrams8
	8.3	Feature Description9
	8.4	Device Functional Modes 11
9	Арр	lication and Implementation 13

	9.1	Application Information	13
	9.2	Typical Application	13
	9.3	System Examples	23
10	Pow	ver Supply Recommendations	25
11	Lay	out	26
	11.1		
	11.2	Layout Example	
	11.3	Thermal Considerations	27
12	Dev	ice and Documentation Support	28
	12.1	Custom Design With WEBENCH® Tools	28
	12.2	Device Support	28
	12.3	Documentation Support	28
	12.4	Related Links	<mark>28</mark>
	12.5	Community Resources	<mark>28</mark>
	12.6	Trademarks	29
	12.7	Electrostatic Discharge Caution	<mark>29</mark>
	12.8	Glossary	29
13		hanical, Packaging, and Orderable mation	20
	mo		

### **4** Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	Added link to WEBENCH® Designer       1         Added "SW (AC), less than 10ns" specification to Absolute Maximum Ratings table       5         Changed T <sub>J</sub> MAX spec from "125" to "150"       5         Added I <sub>Q</sub> and I <sub>SD</sub> specifications       6         Added 125°C plot line in Figure 1 and Figure 4 Typical Characteristics graphic optities       7	
•	Added link to WEBENCH® Designer	1
•	Added "SW (AC), less than 10ns" specification to Absolute Maximum Ratings table	5
•	Changed T <sub>J</sub> MAX spec from "125" to "150"	5
•	Added $I_Q$ and $I_{SD}$ specifications	6
•	Added 125°C plot line in Figure 1 and Figure 4 Typical Characteristics graphic entities.	7

#### Changes from Revision C (September 2013) to Revision D

•	<ul> <li>Added Device Information and ESD Ratings tables, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section</li> </ul>			
С	Changes from Revision B (August 2013) to Revision C	Page		
	Changed 50mV/us to 50mV/s in Enable / Shutdown (EN) section			

# Changes from Revision A (March 2012) to Revision B

•	Added note to Terminal Functions	. 4
•	Changed Equation 13	25
•	Added diode to Figure 41	25

#### 2

### Page

Page



#### TPS62160, TPS62161, TPS62162, TPS62163

SLVSAM2E - NOVEMBER 2011 - REVISED MAY 2017

#### Changes from Original (November 2011) to Revision A

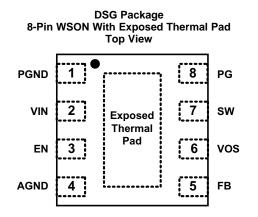
Page Changed data sheet from mixed status to production data...... 1 

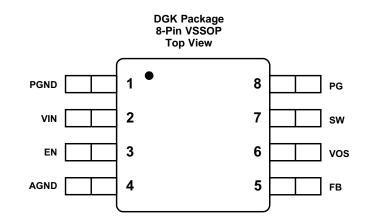
### 5 Device Voltage Options

OUTPUT VOLTAGE <sup>(1)</sup>	PART NUMBER	PACKAGE
adjustable	TPS62160	
1.8 V	TPS62161	
3.3 V	TPS62162	WSON (8)
5.0 V	TPS62163	
adjustable	TPS62160	VSSOP (8)

(1) Contact the factory to check availability of other fixed output voltage versions.

#### Pin Configuration and Functions 6





#### **Pin Functions**

PIN <sup>(1)</sup>		1/0	DESCRIPTION	
NAME	NO.	I/O	DESCRIPTION	
PGND	1	—	Power ground	
VIN	2	I	Supply voltage	
EN	3	I	Enable input (High = enabled, Low = disabled)	
AGND	4	—	Analog ground	
FB	5	I	Voltage feedback of adjustable version. Connect resistive voltage divider to this pin. It is recommended to connect FB to AGND on fixed output voltage versions for improved thermal performance.	
VOS	6	Ι	Output voltage sense pin and connection for the control loop circuitry.	
SW	7	0	Switch node, which is connected to the internal MOSFET switches. Connect inductor between SW and output capacitor.	
PG	8	0	Output power good (High = VOUT ready, Low = VOUT below nominal regulation); open drain (requires pull-up resistor; goes high impedance, when device is switched off)	
Exposed Thermal Pad <sup>(2)</sup>			Must be connected to AGND. Must be soldered to achieve appropriate power dissipation and mechanical reliability.	

For more information about connecting pins, see *Detailed Description* and *Application Information* sections.
 The exposed thermal pad is available with the DSG package only, not with DGK package.

4



www.ti.com



### 7 Specifications

### 7.1 Absolute Maximum Ratings<sup>(1)</sup>

		MIN	MAX	UNIT
	VIN	-0.3	20	V
Operating junction temperature, T <sub>J</sub>	EN, SW (DC)	-0.3	V <sub>IN</sub> + 0.3	N/
	SW (AC), less than 10ns <sup>(3)</sup>	-2	24.5	v
	FB, PG, VOS	-0.3	7	V
Power good sink current	PG		10	mA
Operating junction temperature, T <sub>J</sub>		-40	150	°C
Storage temperature, T <sub>stg</sub>		-65	150	°C

Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
 All voltages are with respect to network ground terminal.

(2) All voltages are with(3) While switching.

#### (5) While Switching.

#### 7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	±2000	
V <sub>(ES</sub>	D) Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all $pins^{(2)}$	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

#### 7.3 Recommended Operating Conditions

	MIN	NOM MAX	UNIT
Supply Voltage, V <sub>IN</sub>	3	17	V
Output Voltage, V <sub>OUT</sub>	0.9	6	V
Operating junction temperature, T <sub>J</sub>	-40	125	°C

#### 7.4 Thermal Information

		TPS	UNIT	
	THERMAL METRIC <sup>(1)</sup>	DSG (WSON) DGK (VSSOP		
		8 PINS	8 PINS	
$R_{\thetaJA}$	Junction-to-ambient thermal resistance	61.8	184.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	61.3	74.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	15.5	105.8	°C/W
ΨJT	Junction-to-top characterization parameter	0.4	13.3	°C/W
ΨЈВ	Junction-to-board characterization parameter	15.4	104.2	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	8.6	_	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

#### TPS62160, TPS62161, TPS62162, TPS62163

SLVSAM2E - NOVEMBER 2011 - REVISED MAY 2017

#### 7.5 Electrical Characteristics

Over junction temperature range ( $T_J = -40^{\circ}$ C to +125°C), typical values at  $V_{IN} = 12$  V and  $T_J = 25^{\circ}$ C (unless otherwise noted)

	PARAMETER	TEST	MIN	TYP	MAX	UNIT		
SUPPLY	1							
V <sub>IN</sub>	Input voltage range <sup>(1)</sup>			3		17	V	
lo	Operating quiescent current	EN = High, I <sub>OUT</sub> = 0 mA, device not switching		17		30	μA	
			$T_J = -40^{\circ}C \text{ to } +85^{\circ}C$		17	25		
SD	Shutdown current <sup>(2)</sup>	EN = Low	T (000 / 0500		1.5	25	– uA	
			$T_{J} = -40^{\circ}C \text{ to } +85^{\circ}C$		1.5	4		
/ <sub>UVLO</sub>	Undervoltage lockout threshold	Falling input voltage		2.6	2.7	2.82	V	
		Hysteresis			180		mV	
Г <sub>SD</sub>	Thermal shutdown temperature	Rising temperature			160		°C	
	Thermal shutdown hysteresis	Falling temperature						
CONTRO	OL (EN, PG)							
V <sub>EN_H</sub>	High level input threshold voltage (EN)			0.9	0.6		V	
V <sub>EN_L</sub>	Low level input threshold voltage (EN)			0.56	0.3	V		
LKG_EN	Input leakage current (EN)	EN = V <sub>IN</sub> or GND		0.01	1	μA		
	Power good threshold	Rising (%V <sub>OUT</sub> )	92%	95%	98%			
VTH_PG	voltage	Falling (%V <sub>OUT</sub> )	87%	90%	93%			
V <sub>OL_PG</sub>	Power good output low voltage	$I_{PG} = -2 \text{ mA}$		0.07	0.3	V		
LKG PG	Input leakage current (PG)	V <sub>PG</sub> = 1.8 V			1	400	nA	
	SWITCH							
	High-side MOSFET ON-	V <sub>IN</sub> ≥ 6 V			300	600		
_	resistance	V <sub>IN</sub> = 3 V		430		mΩ		
R <sub>DS(ON)</sub>	Low-side MOSFET ON-	V <sub>IN</sub> ≥ 6 V			120	200		
	resistance	V <sub>IN</sub> = 3 V		165		mΩ		
	High-side MOSFET forward current limit <sup>(3)</sup>	$V_{IN} = 12 \text{ V}, \text{ T}_{J} = 25^{\circ}\text{C}$		1.45	1.95	2.45	А	
OUTPU	г	J		1				
V <sub>REF</sub>	Internal reference voltage <sup>(4)</sup>				0.8		V	
ILKG_FB	Pin leakage current (FB)	TPS62160, V <sub>FB</sub> = 1.2 V			5	400	nA	
	Output voltage range (TPS62160)	V <sub>IN</sub> ≥ V <sub>OUT</sub>		0.9		6.0	V	
		PWM mode operation, V <sub>IN</sub>	≥ V <sub>OUT</sub> + 1 V	-3%		3%		
Initial output voltage accuracy <sup>(5)</sup>			-3.5%		4%			
V <sub>OUT</sub>	DC output voltage load regulation <sup>(6)</sup>		Power save mode operation, $C_{OUT} = 22 \ \mu F$ $V_{IN} = 12 \ V, \ V_{OUT} = 3.3 \ V, \ PWM \ mode operation$				%/A	
	DC output voltage line regulation <sup>(6)</sup>	$3 \text{ V} \leq \text{V}_{\text{IN}} \leq 17 \text{ V}, \text{ V}_{\text{OUT}} = 3 \text{ operation}$	3.3 V, I <sub>OUT</sub> = 0.5 A, PWM mode		0.02		%/\	

(1) The device is still functional down to under voltage lockout (see parameter  $V_{UVLO}$ ).

(2) Current into VIN pin.

(3) This is the static current limit. It can be temporarily higher in applications due to internal propagation delay (see *Current Limit and Short Circuit Protection* section).

(4) This is the voltage regulated at the FB pin.

(5) This is the accuracy provided by the device itself (line and load regulation effects are not included). For fixed voltage versions, the (internal) resistive feedback divider is included.

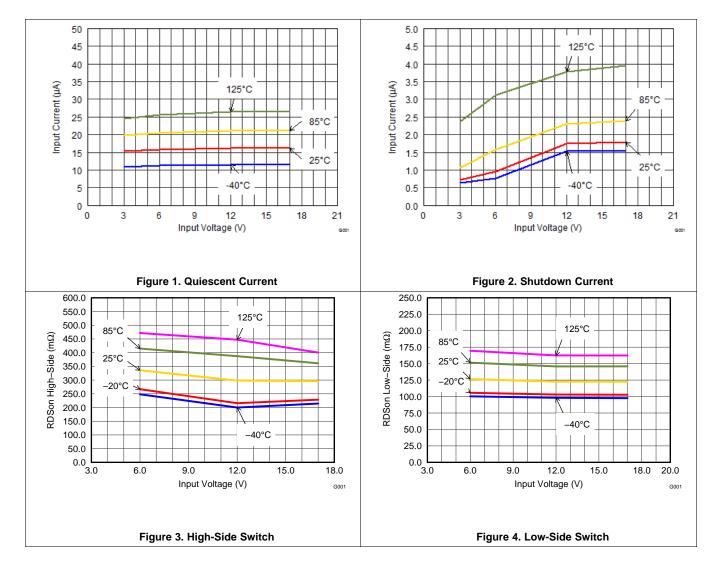
(6) Line and load regulation are depending on external component selection and layout (see Figure 18 and Figure 19).

6

www.ti.com



### 7.6 Typical Characteristics



TEXAS INSTRUMENTS

www.ti.com

### 8 Detailed Description

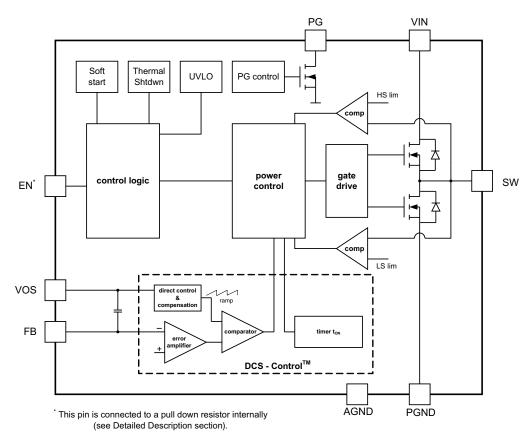
#### 8.1 Overview

The TPS6216x synchronous step-down DC/DC converters are based on DCS-Control<sup>™</sup> (**D**irect **C**ontrol with **S**eamless transition into power save mode), an advanced regulation topology, that combines the advantages of hysteretic, voltage mode and current mode control including an AC loop directly associated to the output voltage. This control loop takes information about output voltage changes and feeds it directly to a fast comparator stage. It sets the switching frequency, which is constant for steady state operating conditions, and provides immediate response to dynamic load changes. To get accurate DC load regulation, a voltage feedback loop is used. The internally compensated regulation network achieves fast and stable operation with small external components and low ESR capacitors.

The DCS-Control<sup>™</sup> topology supports pulse width modulation (PWM) mode for medium and heavy load conditions and a power save mode at light loads. During PWM mode, it operates at its nominal switching frequency in continuous conduction mode. This frequency is typically about 2.25 MHz with a controlled frequency variation depending on the input voltage. If the load current decreases, the converter enters power save mode to sustain high efficiency down to very light loads. In power save mode, the switching frequency decreases linearly with the load current. Since DCS-Control<sup>™</sup> supports both operation modes within one single building block, the transition from PWM to power save mode is seamless without effects on the output voltage.

Fixed output voltage versions provide smallest solution size and lowest current consumption, requiring only 3 external components. An internal current limit supports nominal output currents of up to 1 A.

The TPS6216x family offers both excellent DC voltage and superior load transient regulation, combined with very low output voltage ripple, minimizing interference with RF circuits.



#### 8.2 Functional Block Diagrams



8



### **Functional Block Diagrams (continued)**

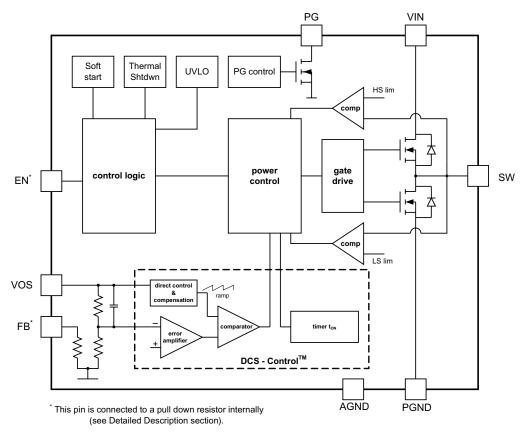


Figure 6. TPS62161/TPS62162/TPS62163 (Fixed Output Voltage)

#### 8.3 Feature Description

#### 8.3.1 Enable and Shutdown (EN)

When enable (EN) is set high, the device starts operation.

Shutdown is forced if EN is pulled low with a shutdown current of typically 1.5  $\mu$ A. During shutdown, the internal power MOSFETs as well as the entire control circuitry are turned off. The internal resistive divider pulls down the output voltage smoothly. If the EN pin is low, an internal pull-down resistor of about 400 k $\Omega$  is connected and keeps it low, to avoid bouncing.

Connecting the EN pin to an appropriate output signal of another power rail provides sequencing of multiple power rails.

#### 8.3.2 Current Limit and Short Circuit Protection

The TPS6216x devices are protected against heavy load and short circuit events. At heavy loads, the current limit determines the maximum output current. If the current limit is reached, the high-side FET is turned off. Avoiding shoot through current, the low-side FET is switched on to allow the inductor current to decrease. The high-side FET turns on again, only if the current in the low-side FET decreases below the low-side current limit threshold of typically 1.2 A.

The output current of the device is limited by the current limit (see *Electrical Characteristics*). Due to internal propagation delay, the actual current can exceed the static current limit during that time. The dynamic current limit is calculated as follows:

Copyright © 2011–2017, Texas Instruments Incorporated

NSTRUMENTS

FXAS

#### www.ti.com

(1)

#### Feature Description (continued)

$$I_{peak(typ)} = I_{LIMF} + \frac{V_L}{L} \cdot t_{PD}$$

where

- I<sub>LIMF</sub> is the static current limit, specified in *Electrical Characteristics*
- L is the inductor value
- V<sub>L</sub> is the voltage across the inductor
- t<sub>PD</sub> is the internal propagation delay

The dynamic high-side switch peak current is calculated as follows:

$$I_{peak(typ)} = I_{LIMF} + \frac{\left(V_{IN} - V_{OUT}\right)}{L} \cdot 30ns$$
<sup>(2)</sup>

Take care with the current limit, if the input voltage is high and very small inductances are used.

#### 8.3.3 Power Good (PG)

The TPS6216x has a built in power good (PG) function to indicate whether the output voltage has reached its appropriate level or not. The PG signal can be used for startup sequencing of multiple rails. The PG pin is an open-drain output that requires a pull-up resistor (to any voltage below 7 V). It can sink 2 mA of current and maintain its specified logic low level. It is high impedance when the device is turned off due to EN, UVLO or thermal shutdown. If not used, the PG pin should be connected to GND but may be left floating.

Davia	e State	PG Logic Status				
Device	e State	High Impedance	Low			
Enable (EN=High)	$V_{FB} \ge V_{TH_PG}$	$\checkmark$				
	$V_{FB} \le V_{TH_PG}$		$\checkmark$			
Shutdown (EN=Low)		$\checkmark$				
UVLO	$0.7 \text{ V} < \text{V}_{\text{IN}} < \text{V}_{\text{UVLO}}$	$\checkmark$				
Thermal Shutdown T <sub>J</sub> > T <sub>SD</sub>		√				
Power Supply Removal V <sub>IN</sub> < 0.7 V		√				

#### Table 1. Power Good Pin Logic Table

#### 8.3.4 Undervoltage Lockout (UVLO)

If the input voltage drops, the under voltage lockout prevents misoperation of the device by switching off both the power FETs. The under voltage lockout threshold is set typically to 2.7 V. The device is fully operational for voltages above the UVLO threshold and turns off if the input voltage trips the threshold. The converter starts operation again once the input voltage exceeds the threshold by a hysteresis of typically 180 mV.

#### 8.3.5 Thermal Shutdown

The junction temperature  $(T_J)$  of the device is monitored by an internal temperature sensor. If  $T_J$  exceeds 160°C (typical), the device goes into thermal shut down. Both the high-side and low-side power FETs are turned off and PG goes high impedance. When  $T_J$  decreases below the hysteresis amount, the converter resumes normal operation, beginning with soft start. To avoid unstable conditions, a hysteresis of typically 20°C is implemented on the thermal shut down temperature.

10 Submit Documentation Feedback

```
Copyright © 2011–2017, Texas Instruments Incorporated
```



#### 8.4 Device Functional Modes

#### 8.4.1 Soft Start

The internal soft start circuitry controls the output voltage slope during startup. This avoids excessive inrush current and ensures a controlled output voltage rise time. It also prevents unwanted voltage drops from high-impedance power sources or batteries. When EN is set to start device operation, the device starts switching after a delay of about 50  $\mu$ s and V<sub>OUT</sub> rises with a slope of about 25 mV/ $\mu$ s. See Figure 30 and Figure 31 for typical startup operation.

The TPS6216x can start into a pre-biased output. During monotonic pre-biased startup, the low-side MOSFET is not allowed to turn on until the device's internal ramp sets an output voltage above the pre-bias voltage.

#### 8.4.2 Pulse Width Modulation (PWM) Operation

The TPS6216x operates with pulse width modulation in continuous conduction mode (CCM) with a nominal switching frequency of about 2.25 MHz. The frequency variation in PWM is controlled and depends on  $V_{IN}$ ,  $V_{OUT}$  and the inductance. The device operates in PWM mode as long the output current is higher than half the inductor's ripple current. To maintain high efficiency at light loads, the device enters power save mode at the boundary to discontinuous conduction mode (DCM). This happens if the output current becomes smaller than half the inductor's ripple current.

#### 8.4.3 Power Save Mode Operation

The TPS6216x's built in power save mode is entered seamlessly, if the load current decreases. This secures a high efficiency in light load operation. The device remains in power save mode as long as the inductor current is discontinuous.

In power save mode the switching frequency decreases linearly with the load current maintaining high efficiency. The transition into and out of power save mode happens within the entire regulation scheme and is seamless in both directions.

The TPS6216x includes a fixed on-time circuitry. This on-time, in steady-state operation, is estimated as:

$$t_{ON} = \frac{V_{OUT}}{V_{IN}} \cdot 420ns \tag{3}$$

For very small output voltages, the on-time increases beyond the result of Equation 3, to stay above an absolute minimum on-time,  $t_{ON(min)}$ , which is around 80 ns, to limit switching losses. The peak inductor current in PSM is approximated by:

$$I_{LPSM(peak)} = \frac{(V_{IN} - V_{OUT})}{L} \cdot t_{ON}$$
(4)

When  $V_{IN}$  decreases to typically 15% above  $V_{OUT}$ , the TPS6216x does not enter power save mode, regardless of the load current. The device maintains output regulation in PWM mode.

#### 8.4.4 100% Duty-Cycle Operation

The duty cycle of the buck converter is given by  $D = V_{OUT}/V_{IN}$  and increases as the input voltage comes close to the output voltage. In this case, the device starts 100% duty cycle operation turning on the high-side switch 100% of the time. The high-side switch stays turned on as long as the output voltage is below the internal setpoint. This allows the conversion of small input to output voltage differences, such as for longest operation time of battery-powered applications. In 100% duty cycle mode, the low-side FET is switched off.

The minimum input voltage to maintain output voltage regulation, depending on the load current and the output voltage level, is calculated as:

Copyright © 2011–2017, Texas Instruments Incorporated

(5)

#### **Device Functional Modes (continued)**

$$V_{IN(min)} = V_{OUT(min)} + I_{OUT} \left( R_{DS(on)} + R_L \right)$$

where

- I<sub>OUT</sub> is the output current
- $R_{DS(on)}$  is the  $R_{DS(on)}$  of the high-side FET
- R<sub>L</sub> is the DC resistance of the inductor used

12 Submit Documentation Feedback Copyright © 2011–2017, Texas Instruments Incorporated Product Folder Links: TPS62160 TPS62161 TPS62162 TPS62163



### 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

The TPS6216x device family are easy to use synchronous step-down DC/DC converters optimized for applications with high power density. A high switching frequency of typically 2.25 MHz allows the use of small inductors and provides fast transient response as well as high output voltage accuracy by utilization of the DCS-Control<sup>™</sup> topology. With its wide operating input voltage range of 3 V to 17 V, the devices are ideally suited for systems powered from either a Li-Ion or other battery as well as from 12-V intermediate power rails. It supports up to 1-A continuous output current at output voltages between 0.9 V and 6 V (with 100% duty cycle mode).

#### 9.2 Typical Application

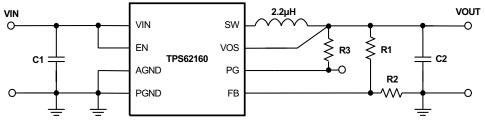


Figure 7. TPS62160 Adjustable Power Supply

#### 9.2.1 Design Requirements

The design guideline provides a component selection to operate the device within the *Recommended Operating Conditions*.

#### 9.2.2 Detailed Design Procedure

#### 9.2.2.1 Custom Design with WEBENCH® Tools

Click here to create a custom design using the TPS62160 device with the WEBENCH® Power Designer.

- 1. Start by entering your  $V_{IN}$ ,  $V_{OUT}$ , and  $I_{OUT}$  requirements.
- 2. Optimize your design for key parameters like efficiency, footprint and cost using the optimizer dial and compare this design with other possible solutions from Texas Instruments.
- 3. The WEBENCH Power Designer provides you with a customized schematic along with a list of materials with real time pricing and component availability.
- 4. In most cases, you will also be able to:
  - Run electrical simulations to see important waveforms and circuit performance
  - Run thermal simulations to understand the thermal performance of your board
  - Export your customized schematic and layout into popular CAD formats
  - Print PDF reports for the design, and share your design with colleagues
- 5. Get more information about WEBENCH tools at www.ti.com/WEBENCH.

Copyright © 2011–2017, Texas Instruments Incorporated

#### Typical Application (continued)

#### 9.2.2.2 Programming the Output Voltage

While the output voltage of the TPS62160 is adjustable, the TPS62161/TPS62162/TPS62163 are programmed to fixed output voltages. For fixed output versions, the FB pin is pulled down internally and may be left floating. It is recommended to connect it to AGND to improve thermal resistance. The adjustable version can be programmed for output voltages from 0.9 V to 6 V by using a resistive divider from VOUT to AGND. The voltage at the FB pin is regulated to 800 mV. The value of the output voltage is set by the selection of the resistive divider from Equation 6. It is recommended to choose resistor values which allow a current of at least 2 µA, meaning the value of R2 should not exceed 400 kΩ. Lower resistor values are recommended for highest accuracy and most robust design. For applications requiring lowest current consumption, the use of fixed output voltage versions is recommended.

$$\mathsf{R}_1 = \mathsf{R}_2 \bigg( \frac{\mathsf{V}_{\mathsf{OUT}}}{0.8\mathsf{V}} - 1 \bigg) \tag{6}$$

If the FB pin becomes open, the device clamps the output voltage at the VOS pin to about 7.4 V.

#### 9.2.2.3 External Component Selection

The external components have to fulfill the needs of the application, but also the stability criteria of the devices control loop. The TPS6216x is optimized to work within a range of external components. The LC output filter's inductance and capacitance have to be considered together, creating a double pole, responsible for the corner frequency of the converter (see Output Filter and Loop Stability section). Table 2 can be used to simplify the output filter component selection. Checked cells represent combinations that are proven for stability by simulation and lab test. Further combinations should be checked for each individual application.

	4.7µF	10µF	22µF	47µF	100µF	200µF	400µF
1µH							
2.2µH		$\checkmark$	√ <sup>(2)</sup>	$\checkmark$	$\checkmark$	$\checkmark$	
3.3µH		$\checkmark$	$\checkmark$	$\checkmark$	$\checkmark$		
4.7µH							

Table 2. Recommended LC Output Filter Combinations<sup>(1)</sup>

The values in the table are nominal values. Variations of typically ±20% due to tolerance, saturation and DC bias are assumed. (1)

This LC combination is the standard value and recommended for most applications. (2)

More detailed information on further LC combinations can be found in SLVA463.

#### 9.2.2.4 Inductor Selection

The inductor selection is affected by several effects like inductor ripple current, output ripple voltage, PWM-to-PSM transition point and efficiency. In addition, the inductor selected has to be rated for appropriate saturation current and DC resistance (DCR). Equation 7 and Equation 8 calculate the maximum inductor current under static load conditions.

$$I_{L(max)} = I_{OUT(max)} + \frac{\Delta I_{L(max)}}{2}$$

(7)



$$\Delta I_{L(\max)} = V_{OUT} \cdot \left( \frac{1 - \frac{V_{OUT}}{V_{IN(\max)}}}{L_{(\min)} \cdot f_{SW}} \right)$$

where

- I<sub>L</sub>(max) is the maximum inductor current
- $\Delta I_L$  is the peak-to-peak inductor ripple current
- L(min) is the minimum effective inductor value
- f<sub>SW</sub> is the actual PWM switching frequency

(8)

(9)

TPS62160, TPS62161, TPS62162, TPS62163 SLVSAM2E – NOVEMBER 2011 – REVISED MAY 2017

Calculating the maximum inductor current using the actual operating conditions gives the minimum saturation current of the inductor needed. A margin of about 20% is recommended to add. A larger inductor value is also useful to get lower ripple current, but increases the transient response time and size as well. The following inductors have been used with the TPS6216x and are recommended for use:

Туре	Inductance [µH]	Current [A] <sup>(2)</sup>	Dimensions [L x B x H] mm	Manufacturer
VLF3012ST-2R2M1R4	2.2 µH, ±20%	1.9 A	3.0 x 2.8 x 1.2	TDK
VLF302512MT-2R2M	2.2 μH, ±20%	1.9 A	3.0 x 2.5 x 1.2	TDK
VLS252012T-2R2M1R3	2.2 uH, ±20%	1.3 A	2.5 x 2.0 x 1.2	TDK
XFL3012-222MEC	2.2 μH, ±20%	1.9 A	3.0 x 3.0 x 1.2	Coilcraft
XFL3012-332MEC	3.3 µH, ±20%	1.6 A	3.0 x 3.0 x 1.2	Coilcraft
LPS3015-332ML_	3.3 uH, ±20%	1.4 A	3.0 x 3.0 x 1.4	Coilcraft
NR3015T-2R2M	2.2 uH, ±20%	1.5 A	3.0 x 3.0 x 1.5	Taiyo Yuden
744025003	3.3 uH, ±20%	1.5 A	2.8 x 2.8 x 2.8	Wuerth
PSI25201B-2R2MS	2.2 uH, ±20%	1.3 A	2.0 x 2.5 x 1.2	Cyntec

#### Table 3. List of Inductors<sup>(1)</sup>

(1) See the *Third-Party Products Disclaimer*.

(2)  $I_{RMS}$  at 40°C rise or  $I_{SAT}$  at 30% drop.

The TPS6216x can operate with an inductor as low as 2.2  $\mu$ H. However, for applications with low input voltages, 3.3  $\mu$ H is recommended to allow the full output current. The inductor value also determines the load current at which Power Save Mode is entered:

$$I_{load(PSM)} = \frac{1}{2} \Delta I_L$$

Using Equation 8, this current level is adjusted by changing the inductor value.

#### 9.2.2.5 Capacitor Selection

#### 9.2.2.5.1 Output Capacitor

The recommended value for the output capacitor is 22 uF. The architecture of the TPS6216x allows the use of tiny ceramic output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get narrow capacitance variation with temperature, it is recommended to use an X7R or X5R dielectric. Using a higher value can have some advantages like smaller voltage ripple and a tighter DC output accuracy in power save mode (see SLVA463).

Note: In power save mode, the output voltage ripple depends on the output capacitance, its ESR and the peak inductor current. Using ceramic capacitors provides small ESR and low ripple.

Copyright © 2011–2017, Texas Instruments Incorporated

#### 9.2.2.5.2 Input Capacitor

For most applications, 10  $\mu$ F is sufficient and is recommended, though a larger value reduces input current ripple further. The input capacitor buffers the input voltage for transient events and also decouples the converter from the supply. A low ESR multilayer ceramic capacitor is recommended for best filtering and should be placed between VIN and PGND as close as possible to those pins.

#### NOTE

**DC bias effect:** High capacitance ceramic capacitors have a DC bias effect, which has a strong influence on the final effective capacitance. Therefore the right capacitor value has to be chosen carefully. Package size and voltage rating in combination with dielectric material are responsible for differences between the rated capacitor value and the effective capacitance.

#### 9.2.2.6 Output Filter and Loop Stability

1

 $f_{pole} = \frac{1}{2\pi \cdot 25 \pi E} \cdot \left(\frac{1}{R} + \frac{1}{R}\right)$ 

The devices of the TPS6216x family are internally compensated to be stable with L-C filter combinations corresponding to a corner frequency calculated with Equation 10:

$$f_{LC} = \frac{1}{2\pi\sqrt{L\cdot C}} \tag{10}$$

Proven nominal values for inductance and ceramic capacitance are given in Table 2 and are recommended for use. Different values may work, but care has to be taken on the loop stability which is affected. More information including a detailed L-C stability matrix is found in SLVA463.

The TPS6216X devices, both fixed and adjustable versions, include an internal 25 pF feed forward capacitor, connected between the VOS and FB pins. This capacitor impacts the frequency behavior and sets a pole and zero in the control loop with the resistors of the feedback divider, per Equation 11 and Equation 12:

$$f_{zero} = \frac{1}{2\pi \cdot R_1 \cdot 25pF} \tag{11}$$

$$2\pi \cdot 25 pr \quad (R_1 \quad R_2)$$
(12)  
Though the TPS6216x devices are stable without the pole and zero being in a particular location, adjusting their

location to the specific needs of the application can provide better performance in power save mode and/or improved transient response. An external feed-forward capacitor can also be added. A more detailed discussion on the optimization for stability versus transient response can be found in SLVA289 and SLVA466.

If using ceramic capacitors, the DC bias effect has to be considered. The DC bias effect results in a drop in effective capacitance as the voltage across the capacitor increases (see **NOTE** in *Input Capacitor* section).

#### 9.2.2.7 TPS6216x Components List

Table 4 shows the list of components for the *Application Curves*.



#### TPS62160, TPS62161, TPS62162, TPS62163

SLVSAM2E - NOVEMBER 2011 - REVISED MAY 2017

#### www.ti.com

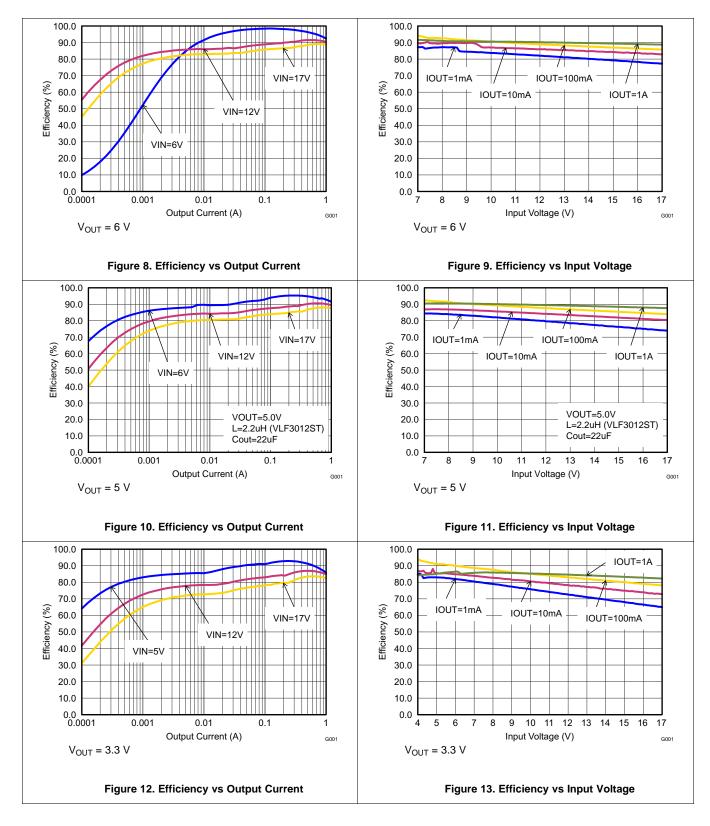
# Table 4. List of Components

REFERENCE	DESCRIPTION	MANUFACTURER
IC	17 V, 1 A Step-Down Converter, WSON	TPS62160DSG, Texas Instruments
L1	2.2 μH, 1.4 A, 3 mm x 2.8 mm x 1.2 mm	VLF3012ST-2R2M1R4, TDK
C1	10 µF, 25 V, Ceramic, 0805	Standard
C2	22 µF, 6.3 V, Ceramic, 0805	Standard
R1	depending on V <sub>OUT</sub>	
R2	depending on V <sub>OUT</sub>	
R3	100 kΩ, Chip, 0603, 1/16 W, 1%	Standard

SLVSAM2E - NOVEMBER 2011 - REVISED MAY 2017

#### 9.2.3 Application Curves

 $V_{IN}$ =12 V,  $V_{OUT}$ =3.3 V,  $T_A$ =25°C, (unless otherwise noted)



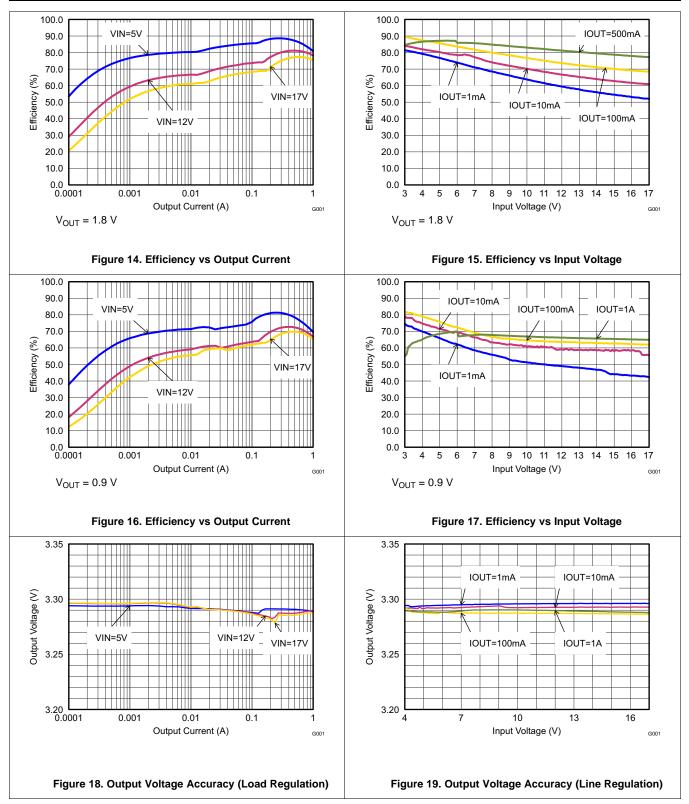


www.ti.com



#### TPS62160, TPS62161, TPS62162, TPS62163

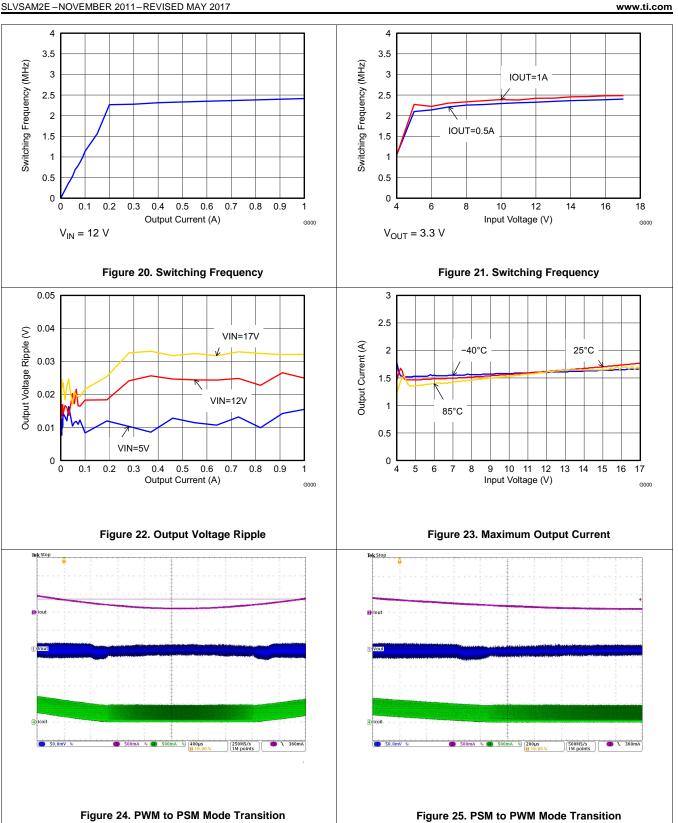
SLVSAM2E - NOVEMBER 2011 - REVISED MAY 2017





### TPS62160, TPS62161, TPS62162, TPS62163

SLVSAM2E - NOVEMBER 2011-REVISED MAY 2017

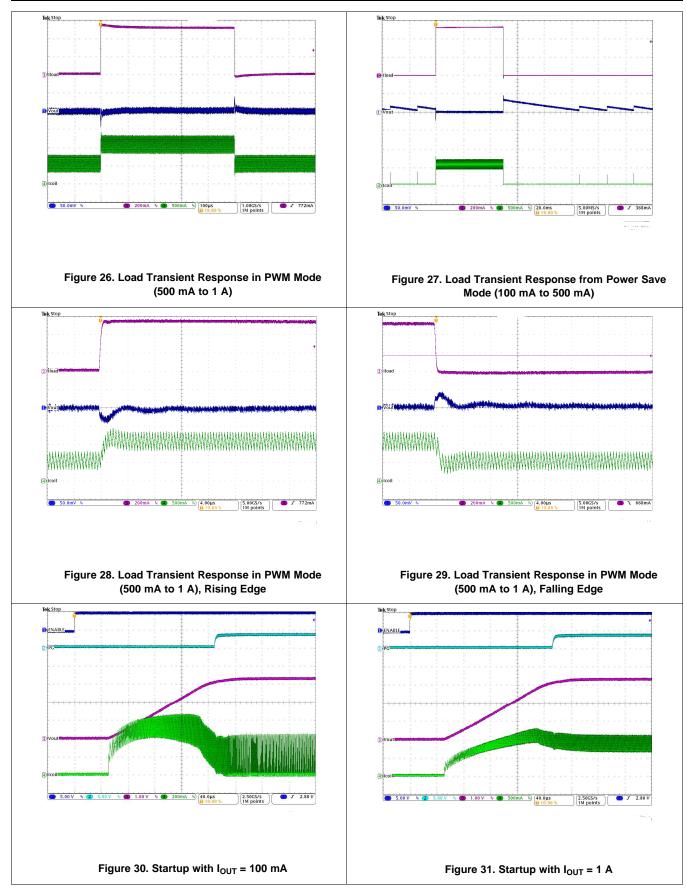


Copyright © 2011–2017, Texas Instruments Incorporated



#### TPS62160, TPS62161, TPS62162, TPS62163

SLVSAM2E - NOVEMBER 2011 - REVISED MAY 2017



Copyright © 2011–2017, Texas Instruments Incorporated

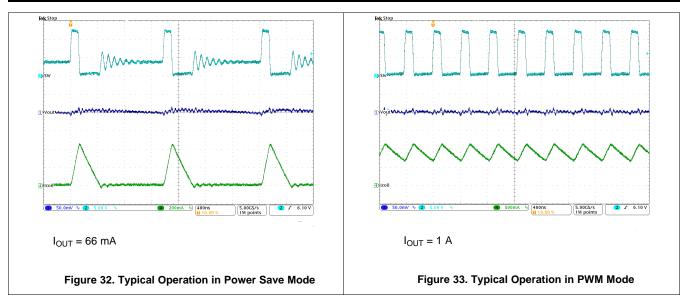
Submit Documentation Feedback

Product Folder Links: TPS62160 TPS62161 TPS62162 TPS62163



# TPS62160, TPS62161, TPS62162, TPS62163

SLVSAM2E - NOVEMBER 2011 - REVISED MAY 2017





#### 9.3 System Examples

#### 9.3.1 1-A Power Supply

The following example circuits show various TPS6216x devices and input voltages that provide a 1-A power supply with output voltage options.

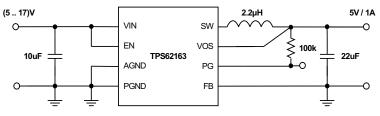


Figure 34. 5 V / 1 A Power Supply

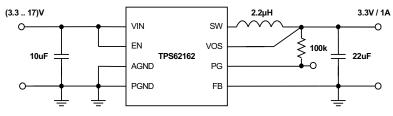


Figure 35. 3.3 V / 1 A Power Supply

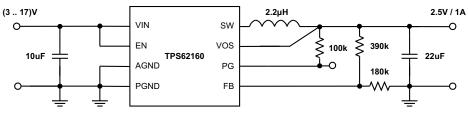
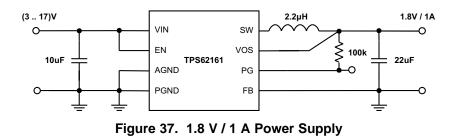
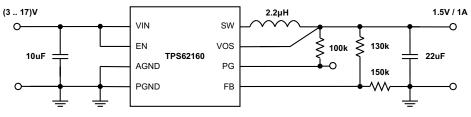


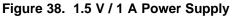
Figure 36. 2.5 V / 1 A Power Supply





### System Examples (continued)





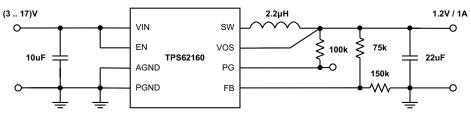


Figure 39. 1.2 V / 1 A Power Supply

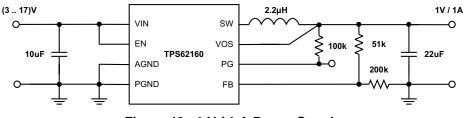


Figure 40. 1 V / 1 A Power Supply



#### System Examples (continued)

#### 9.3.2 Inverting Power Supply

The TPS6216x can be used as inverting power supply by rearranging external circuitry as shown in Figure 41. As the former GND node now represents a voltage level below system ground, the voltage difference between  $V_{IN}$  and  $V_{OUT}$  has to be limited for operation to the maximum supply voltage of 17 V (see Equation 13).

 $V_{IN} + |V_{OUT}| \le V_{IN max}$ 

(13)

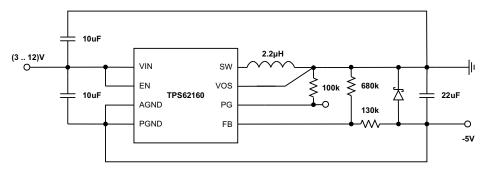


Figure 41. –5 V Inverting Power Supply

The transfer function of the inverting power supply configuration differs from the buck mode transfer function, incorporating a right half plane zero additionally. The loop stability has to be adapted and an output capacitance of at least 22  $\mu$ F is recommended. A detailed design example is given in SLVA469.

#### **10** Power Supply Recommendations

The TPS6216x device family has no special requirements for its input power supply. The input power supply's output current needs to be rated according to the supply voltage, output voltage, and output current of the TPS6216x.

TEXAS INSTRUMENTS

www.ti.com

### 11 Layout

#### 11.1 Layout Guidelines

A proper layout is critical for the operation of a switched mode power supply, even more at high switching frequencies. Therefore the PCB layout of the TPS6216x demands careful attention to ensure operation and to get the performance specified. A poor layout can lead to issues like poor regulation (both line and load), stability and accuracy weaknesses, increased EMI radiation, and noise sensitivity.

Provide low inductive and resistive paths to ground for loops with high di/dt. Therefore paths conducting the switched load current should be as short and wide as possible. Provide low capacitive paths, with respect to all other nodes, for wires with high dv/dt. Therefore the input and output capacitance should be placed as close as possible to the IC pins and parallel wiring over long distances as well as narrow traces should be avoided. Loops which conduct an alternating current should outline an area as small as possible, as this area is proportional to the energy radiated.

Also sensitive nodes like FB and VOS should be connected with short wires, not nearby high dv/dt signals, such as SW. As they carry information about the output voltage, they should be connected as close as possible to the actual output voltage (at the output capacitor). Signals not assigned to power transmission, such as the feedback divider, should refer to the signal ground (AGND) and always be separated from the power ground (PGND).

In summary, the input capacitor should be placed as close as possible to the VIN and PGND pin of the IC. This connections should be done with wide and short traces. The output capacitor should be placed such that its ground is as close as possible to the IC's PGND pins - avoiding additional voltage drop in traces. This connection should also be made short and wide. The inductor should be placed close to the SW pin and connect directly to the output capacitor - minimizing the loop area between the SW pin, inductor, output capacitor and PGND pin. The feedback resistors,  $R_1$  and  $R_2$ , should be placed close to the IC and connect directly to the AGND and FB pins. Those connections (including VOUT) to the resistors and especially to the VOS pin should stay away from noise sources, such as the inductor. The VOS pin should connect in the shortest way to VOUT at the output capacitor, while the VOUT connection to the feedback divider can connect at the load.

A single point grounding scheme should be implemented with all grounds (AGND, PGND and the thermal pad) connecting at the IC's exposed thermal pad. See Figure 42 for the recommended layout of the TPS6216x. More detailed information can be found in the EVM Users Guide, SLVU483.

The exposed thermal pad must be soldered to the circuit board for mechanical reliability and to achieve appropriate power dissipation. Although the exposed thermal pad can be connected to a floating circuit board trace, the device has better thermal performance if it is connected to a larger ground plane. The exposed thermal pad is electrically connected to AGND.

# 

11.2 Layout Example

Figure 42. TPS6216x Board Layout



#### **11.3 Thermal Considerations**

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

Three basic approaches for enhancing thermal performance are listed below:

- Improving the power dissipation capability of the PCB design
- Improving the thermal coupling of the component to the PCB by soldering the exposed thermal pad
- Introducing airflow in the system

For more details on how to use the thermal parameters, see the application reports *Thermal Characteristics of Linear and Logic Packages Using JEDEC PCB Designs*, SZZA017 and *Semiconductor and IC Package Thermal Metrics*, SPRA953.

The TPS6216x is designed for a maximum operating junction temperature  $(T_J)$  of 125°C. Therefore the maximum output power is limited by the power losses that can be dissipated over the actual thermal resistance, given by the package and the surrounding PCB structures. If the thermal resistance of the package is given, the size of the surrounding copper area and a proper thermal connection of the IC can reduce the thermal resistance. To get an improved thermal behavior, TI recommends to use top layer metal to connect the device with wide and thick metal lines. Internal ground layers can connect to vias directly under the IC for improved thermal performance.

If short circuit or overload conditions are present, the device is protected by limiting internal power dissipation.

### Texas Instruments

# **12 Device and Documentation Support**

# 12.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPS62160 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage ( $V_{IN}$ ), output voltage ( $V_{OUT}$ ), and output current ( $I_{OUT}$ ) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

# 12.2 Device Support

### 12.2.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

# **12.3 Documentation Support**

# 12.3.1 Related Documentation

For related documentation see the following:

- Optimizing the TPS62130/40/50/60/70 Output Filter, SLVA463
- Optimizing Transient Response of Internally Compensated dc-dc Converters With Feedforward Capacitor, SLVA289
- Using a Feedforward Capacitor to Improve Stability and Bandwidth of TPS62130/40/50/60/70, SLVA466
- Thermal Characteristics of Linear and Logic Packages Using JEDEC PCB Designs, SZZA017

# 12.4 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TPS62160	Click here	Click here	Click here	Click here	Click here
TPS62161	Click here	Click here	Click here	Click here	Click here
TPS62162	Click here	Click here	Click here	Click here	Click here
TPS62163	Click here	Click here	Click here	Click here	Click here

#### Table 5. Related Links

### 12.5 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.



#### **Community Resources (continued)**

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.6 Trademarks

DCS-Control, E2E are trademarks of Texas Instruments. WEBENCH is a registered trademark of Texas Instruments. All other trademarks are the property of their respective owners.

#### 12.7 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 12.8 Glossary

#### SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

#### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### PACKAGING INFORMATION

Orderable	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
part number	(1)	(2)			(3)	(4)	(5)		(6)
TPS62160DGKR	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	NIPDAUAG   SN	Level-1-260C-UNLIM	-40 to 125	62160
TPS62160DGKT	Active	Production	VSSOP (DGK)   8	250   SMALL T&R	Yes	NIPDAUAG   SN	Level-1-260C-UNLIM	-40 to 125	62160
TPS62160DSGR	Active	Production	WSON (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QTV
TPS62160DSGT	Active	Production	WSON (DSG)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QTV
TPS62161DSGR	Active	Production	WSON (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QUB
TPS62161DSGT	Active	Production	WSON (DSG)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QUB
TPS62162DSGR	Active	Production	WSON (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QUC
TPS62162DSGT	Active	Production	WSON (DSG)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QUC
TPS62163DSGR	Active	Production	WSON (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QUD
TPS62163DSGT	Active	Production	WSON (DSG)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QUD

<sup>(1)</sup> **Status:** For more details on status, see our product life cycle.

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



# PACKAGE OPTION ADDENDUM

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF TPS62160, TPS62162 :

Automotive : TPS62160-Q1, TPS62162-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

Texas

STRUMENTS

### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62160DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
TPS62160DGKT	VSSOP	DGK	8	250	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
TPS62160DSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62160DSGT	WSON	DSG	8	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62160DSGT	WSON	DSG	8	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS62161DSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62161DSGT	WSON	DSG	8	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62162DSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62162DSGT	WSON	DSG	8	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62163DSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS62163DSGT	WSON	DSG	8	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2



# PACKAGE MATERIALS INFORMATION

5-Nov-2024



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62160DGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
TPS62160DGKT	VSSOP	DGK	8	250	366.0	364.0	50.0
TPS62160DSGR	WSON	DSG	8	3000	210.0	185.0	35.0
TPS62160DSGT	WSON	DSG	8	250	210.0	185.0	35.0
TPS62160DSGT	WSON	DSG	8	250	205.0	200.0	33.0
TPS62161DSGR	WSON	DSG	8	3000	210.0	185.0	35.0
TPS62161DSGT	WSON	DSG	8	250	210.0	185.0	35.0
TPS62162DSGR	WSON	DSG	8	3000	210.0	185.0	35.0
TPS62162DSGT	WSON	DSG	8	250	210.0	185.0	35.0
TPS62163DSGR	WSON	DSG	8	3000	210.0	185.0	35.0
TPS62163DSGT	WSON	DSG	8	250	210.0	185.0	35.0

# DSG 8

2 x 2, 0.5 mm pitch

# **GENERIC PACKAGE VIEW**

# WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





# DSG0008A



# **PACKAGE OUTLINE**

# WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



# DSG0008A

# **EXAMPLE BOARD LAYOUT**

# WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

 This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

 Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



# DSG0008A

# **EXAMPLE STENCIL DESIGN**

# WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



# **DGK0008A**



# **PACKAGE OUTLINE**

# VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



# DGK0008A

# **EXAMPLE BOARD LAYOUT**

# <sup>™</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown

on this view. It is recommended that vias under paste be filled, plugged or tented.

9. Size of metal pad may vary due to creepage requirement.



# DGK0008A

# **EXAMPLE STENCIL DESIGN**

# <sup>™</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

12. Board assembly site may have different recommendations for stencil design.



### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated